




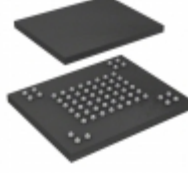
	<p><b>NAND01GW3B2AN6E</b></p>
	<p><b>Manufacturer Part Number:</b> NAND01GW3B2AN6E</p> <p><b>Manufacturer/Brand:</b> STMicroelectronics</p> <p><b>Part of Description:</b> IC FLASH 1GBIT 50NS 48TSOP</p> <p><b>Datasheets:</b>  <a href="#">NAND01GW3B2AN6E.pdf</a></p> <p><b>RoHs Status:</b>  Lead free / RoHS Compliant</p> <p><b>Stock Condition:</b> New original, 2466 pcs Stock Available.</p> <p><b>Ship From:</b> Hong Kong</p> <p><b>Shipment Way:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	NAND01GW3B2AN6E
Manufacturer	STMicroelectronics
Description	IC FLASH 1GBIT 50NS 48TSOP
Category	Integrated Circuits (ICs) > Memory
Part Status	2466 pcs Stock
Series	-
Operating Temperature	-40°C ~ 85°C (TA)
Interface	Parallel
Package / Case	48-TFSOP (0.724", 18.40mm Width)
Supplier Device Package	48-TSOP
Voltage - Supply	2.7 V ~ 3.6 V
Memory Type	Non-Volatile
Speed	-
Memory Size	1Gb (128M x 8)
Memory Format	FLASH
Packaging	Tray

NAND01GW3B2AN6E is New Original in Stock, Search NAND01GW3B2AN6E Datasheets, PDF, Inventory at Y-IC.com Online, Order NAND01GW3B2AN6E STMicroelectronics with warrantied and confidence. RFQ NAND01GW3B2AN6E : Info@Y-IC.com

You May Be Also Be interested In:

 <b>NAND01GW3B2AN6</b> ST NAND01GW3B2AN6 ST	 <b>NAND01GW382CZA6</b> NUMONYX NAND01GW382CZA6 NUMONYX	 <b>NAND01GW3B2AN6F</b> STMicroelectronics IC FLASH 1GBIT 50NS 48TSOP	 <b>NAND01GW3B2BN6E</b> ST NAND01GW3B2BN6E ST
 <b>NAND01GW3B2BN6</b> ST NAND01GW3B2BN6 ST	 <b>NAND01GW3A2AN6E</b> STMicroelectronics IC FLASH 1GBIT 50NS 48TSOP	 <b>NAND01GW3B2BZA6E</b> Micron Technology IC FLASH 1GBIT 30NS 63VFBGA	 <b>NAND01GW3B2AZA6E</b> STMicroelectronics IC FLASH 1GBIT 50NS 63VFBGA

Hot Parts

More

- |  |  |  |   |  |
|--|--|--|---|--|
|  NAND01GR3B2CZA6E |  NAND01GW3B2CN6E    |  NAND02GR3B2CZA6E |  NAND02GR3B2DZA6  |  NAND02GW3B2DN6   |
|  NAND02GW3B2DN6E  |  NAND02GW3B2DZA6    |  NAND04GW3B2DN6E  |  NAND04GW3C2BN6E  |  NAND128W3A0BN6   |
|  NAND128W3A2BN6   |  NAND128W3A2BN6E    |  NAND128W3AABN6F  |  NAND256W3A0AN6   |  NAND256W3A2BN6   |
|  NAND256W3A2BN6E  |  NAND256W3A2BN6F    |  NAND256W3A2BNX   |  NAND256W3A2BZA6E |  NAND256W3A2BZA6F |
|  NAND512R3A2CZA6E |  NAND512R3A2SZA6E   |  NAND512W3A-2SN6  |  NAND512W3A2BN6E  |  NAND512W3A2BZA6  |
|  NAND512W3A2BZA6E |  NAND512W3A2CN6F    |  NAND512W3A2DN6   |  NAND512W3A2DZA6E |  NAND512W3A2SN6   |
|  NAND512W3A2SNX   |  NAND512W3A2SZA6E   |  NAND512W3A2SZAXE |  NANDA8R3N0AP4E5F |  NANDA8R3N0AZBB5  |
|  NANDA8R3N0AZBB5E |  NANDA9R3N0BZPA5    |  NANDA9R3N0CZPA5F |  NANDA9R4N0AZBA5F |  NANDA9R4N5BZBC5E |
|  NANDA9W3N6CZBB5E |  NANDB2R3N0BP4E5F   |  NANO110SD2BN     |  NANO112LB1AN     |  NANO112LC2AN     |
|  NANO130SD2BN     |  NANOSMD050F/13.2-2 |  NANOSMD075F-2    |  NANOSMD150F-2    |  NANOSMDC012F-2   |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

ADD: Unit A5-B5 No.509, 5/F Sing Win Factory Building, 15-17 Shing yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited